

2MBI1000XRNE120-50

IGBT Modules

Power Module (X series)
1200V / 1000A / 2-in-1 package

■ Features

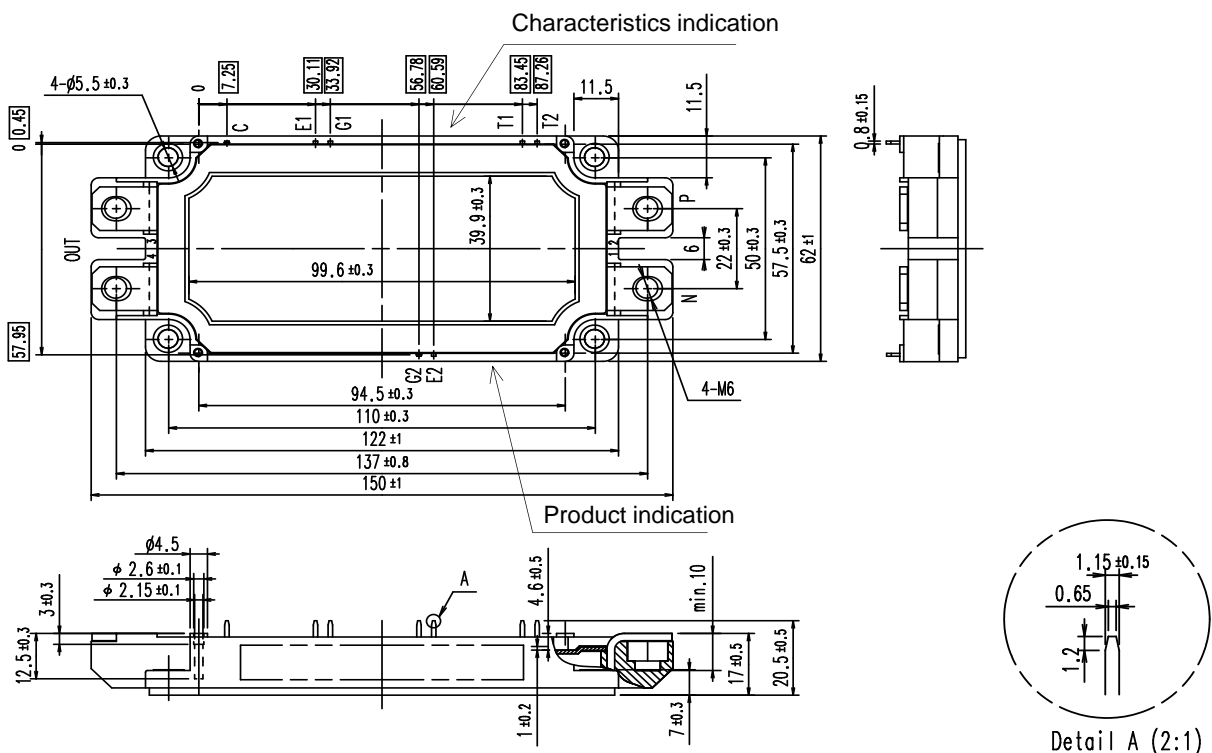
- Low $V_{CE(sat)}$
- Low Inductance Module structure
- Solder pin terminals

■ Applications

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems



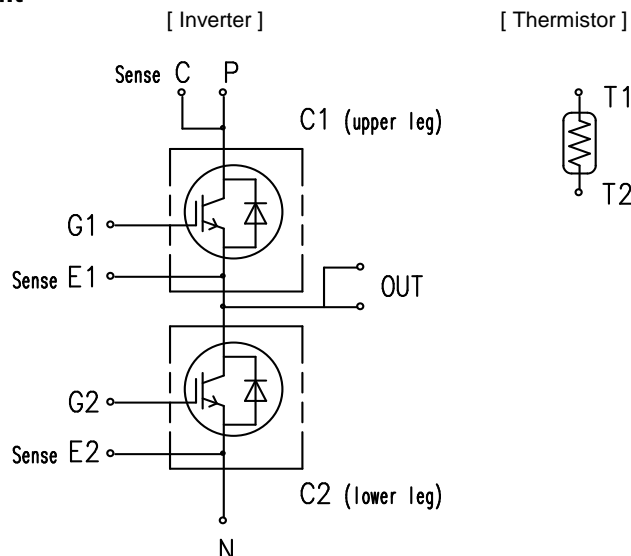
■ Outline drawing (Unit : mm)



NOTE) shows theoretical dimension and tolerance is ± 0.5

Weight: 350 g(typ.)

■ Equivalent Circuit



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■ Absolute Maximum Ratings (at $T_c = 25^\circ\text{C}$ unless otherwise specified)

| Items | | Symbols | Conditions | Maximum Ratings | Units |
|---|--|------------|--------------------------------------|-----------------|------------------|
| Inverter | Collector-emitter voltage, gate-emitter short-circuited | V_{CES} | | 1200 | V |
| | Gate-emitter voltage, collector-emitter short-circuited | V_{GES} | | ± 20 | V |
| | Collector current | I_C | Continuous $T_c = 100^\circ\text{C}$ | 1000 | A |
| | Repetitive peak collector current | I_{CRM} | 1ms | 2000 | |
| | Reverse-conducting current | I_{RC} | | 1000 | |
| | Repetitive peak reverse-conducting current | I_{RCRM} | 1ms | 2000 | |
| | Total power dissipation | P_{tot} | 1 device | 8330 | W |
| | Virtual junction temperature | T_{vj} | | 175 | $^\circ\text{C}$ |
| | Operating virtual junction temperature (under switching conditions) | T_{vjop} | | 175 | |
| | Case temperature | T_c | | 150 | |
| Storage temperature | | T_{stg} | | -40 ~ 150 | |
| Isolation voltage | between terminals and copper base (*1) between thermistor and others (*2) | V_{isol} | AC: 1min. | 4000 | Vrms |
| Mounting torque for screws to heatsink (*3) | | M_s | M5 | 6.0 | N·m |
| Mounting torque for terminal screws (*3) | | M_t | M6 | 6.0 | |

(*1) All terminals should be connected together during the test.

(*2) Two thermistor terminals should be connected together, other terminals should be connected together

(*3) Recommendable Value: : Mounting torque of screws to heatsink 2.5 ~ 6.0 N·m (M5)
Recommendable Value: : Mounting torque of screws to terminals 3.5 ~ 6.0 N·m (M6)



■ Electrical characteristics (at $T_{vj} = 25^\circ\text{C}$ unless otherwise specified)

| Items | | Symbols | Conditions | | Characteristics | | | Units |
|--------------------------|--|-----------------------------|--|-----------------------|-----------------|------|------|----------|
| | | | | | min. | typ. | max. | |
| Inverter | Collector-emitter cut-off current, Collector current | I_{CES} | $V_{GE} = 0V$ $V_{CE} = 1200V$ | | - | - | 200 | μA |
| | Gate leakage current, collector-emitter short-circuited | I_{GES} | $V_{CE}=0V, V_{GE}=\pm 20V$ | | - | - | 400 | nA |
| | Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{CE} = 20V$ $I_C = 1000mA$ | | 5.8 | 6.4 | 7.0 | V |
| | Collector-emitter saturation voltage | $V_{CE(sat)}$ (terminal) | $V_{GE} = 15V$ $I_C = 1000A$ | $T_{vj}=25^{\circ}C$ | - | 2.75 | 3.30 | V |
| | | $V_{CE(sat)}$ (chip) | | $T_{vj}=25^{\circ}C$ | - | 1.55 | 2.00 | |
| | | | | $T_{vj}=125^{\circ}C$ | - | 1.85 | - | |
| | | | | $T_{vj}=150^{\circ}C$ | - | 1.95 | - | |
| | | | | $T_{vj}=175^{\circ}C$ | - | 2.00 | - | |
| | Internal gate resistance | r_g | - | | - | 0.95 | - | Ω |
| | Input capacitance | C_{ies} | $V_{CE}=10V, V_{GE}=0V, f=1MHz$ | | - | 126 | - | nF |
| | Output capacitance | C_{oes} | | | - | 5.3 | - | |
| | Reverse transfer capacitance | C_{res} | | | - | 1.19 | - | |
| | Gate charge | Q_G | $V_{CC} = 600V, I_C = 1000A$ $V_{GE} = -15 \rightarrow +15V$ | | - | 7.8 | - | μC |
| | Reverse-conducting voltage | V_{RC} (terminal) | $V_{GE} = 0V$ $I_{RC}= 1000A$ | $T_{vj}=25^{\circ}C$ | - | 2.80 | 3.30 | V |
| | | V_{RC} (chip) | | $T_{vj}= 25^{\circ}C$ | - | 1.60 | 2.05 | |
| | | | | $T_{vj}=125^{\circ}C$ | - | 1.75 | - | |
| | | | | $T_{vj}=150^{\circ}C$ | - | 1.75 | - | |
| | | | | $T_{vj}=175^{\circ}C$ | - | 1.75 | - | |
| | Turn-on delay time (*1) | $t_{d(on)}$ | $V_{CC} = 600V$ $I_C, I_F = 1000A$ $V_{GE} = +15V / -15V$ $R_G = 0.5\Omega$ $L_S = 35\text{ nH}$ | $T_{vj}= 25^{\circ}C$ | - | 0.42 | - | μs |
| | | | | $T_{vj}=125^{\circ}C$ | - | 0.43 | - | |
| | | | | $T_{vj}=150^{\circ}C$ | - | 0.43 | - | |
| | | | | $T_{vj}=175^{\circ}C$ | - | 0.43 | - | |
| | Rise time | t_r | | $T_{vj}= 25^{\circ}C$ | - | 0.10 | - | |
| | | | | $T_{vj}=125^{\circ}C$ | - | 0.11 | - | |
| | | | | $T_{vj}=150^{\circ}C$ | - | 0.11 | - | |
| | | | | $T_{vj}=175^{\circ}C$ | - | 0.12 | - | |
| Turn-off delay time (*2) | $t_{d(off)}$ | $T_{vj}= 25^{\circ}C$ | | - | 0.54 | - | | |
| | | $T_{vj}=125^{\circ}C$ | | - | 0.55 | - | | |
| | | $T_{vj}=150^{\circ}C$ | | - | 0.56 | - | | |
| | | $T_{vj}=175^{\circ}C$ | | - | 0.56 | - | | |
| Fall time | t_f | $T_{vj}= 25^{\circ}C$ | | - | 0.12 | - | | |
| | | $T_{vj}=125^{\circ}C$ | | - | 0.15 | - | | |
| | | $T_{vj}=150^{\circ}C$ | | - | 0.15 | - | | |
| | | $T_{vj}=175^{\circ}C$ | | - | 0.16 | - | | |
| Forward recovery time | t_{fr} | $T_{vj}= 25^{\circ}C$ | | - | 0.28 | - | | |
| | | $T_{vj}=125^{\circ}C$ | | - | 0.38 | - | | |
| | | $T_{vj}=150^{\circ}C$ | | - | 0.41 | - | | |
| | | $T_{vj}=175^{\circ}C$ | | - | 0.45 | - | | |

(*1) Turn on time (t_{on}) = $t_{d(on)} + t_r$

(*2) Turn off time (t_{off}) = $t_{d(off)} + t_f$

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■ Electrical characteristics (at $T_{vj}=25^{\circ}\text{C}$ unless otherwise specified)

| Items | | Symbols | Conditions | | Characteristics | | | Units |
|------------|---|------------------|---|-------------------------------------|-----------------|-------|----------|-------|
| | | | | | min. | typ. | max. | |
| Inverter | Turn-on energy (per pulse) | E_{on} | $V_{\text{CC}} = 600\text{V}$ | $T_{\text{vj}}=25^{\circ}\text{C}$ | - | 75.7 | - | mJ |
| | | | $I_{\text{C}}, I_{\text{F}} = 1000\text{A}$ | $T_{\text{vj}}=125^{\circ}\text{C}$ | - | 98.9 | - | |
| | | | $V_{\text{GE}} = +15\text{V} / -15\text{V}$ | $T_{\text{vj}}=150^{\circ}\text{C}$ | - | 103.5 | - | |
| | | | $R_{\text{G}} = 0.5\Omega$ | $T_{\text{vj}}=175^{\circ}\text{C}$ | - | 110.5 | - | |
| | Turn-off energy (per pulse) | E_{off} | $L_{\text{S}} = 35\text{ nH}$ | $T_{\text{vj}}=25^{\circ}\text{C}$ | - | 106.6 | - | |
| | | | $T_{\text{vj}}=125^{\circ}\text{C}$ | - | 117.6 | - | | |
| | | | $T_{\text{vj}}=150^{\circ}\text{C}$ | - | 125.3 | - | | |
| | | | $T_{\text{vj}}=175^{\circ}\text{C}$ | - | 134.1 | - | | |
| | Forward recovery energy (per pulse) | E_{fr} | | $T_{\text{vj}}=25^{\circ}\text{C}$ | - | 93.5 | - | |
| | | | | $T_{\text{vj}}=125^{\circ}\text{C}$ | - | 124.7 | - | |
| | | | | $T_{\text{vj}}=150^{\circ}\text{C}$ | - | 137.7 | - | |
| | | | | $T_{\text{vj}}=175^{\circ}\text{C}$ | - | 139.0 | - | |
| Thermistor | Resistance | R | $T = 25^{\circ}\text{C}$ | - | 5000 | - | Ω | |
| | | | $T = 100^{\circ}\text{C}$ | 465 | 495 | 520 | | |
| | B value | B | $T = 25/ 50^{\circ}\text{C}$ | 3305 | 3375 | 3450 | K | |

NOTICE:

The external gate resistance (R_G) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum R_G depends on circuit configuration and/or environment. We recommend that the R_G has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

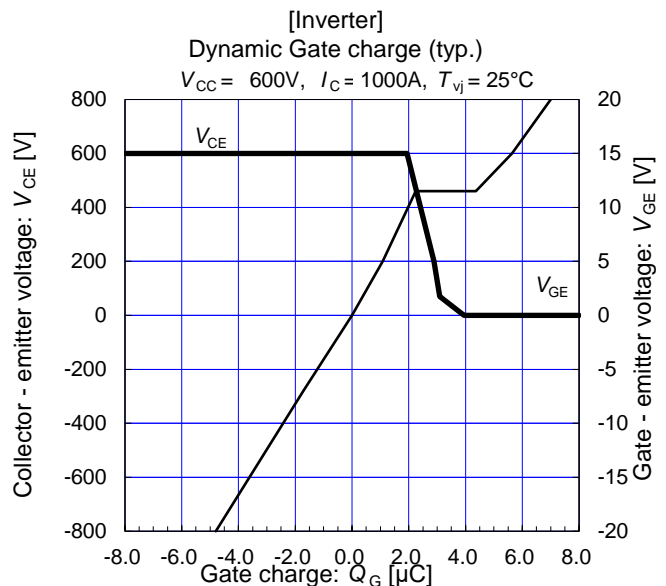
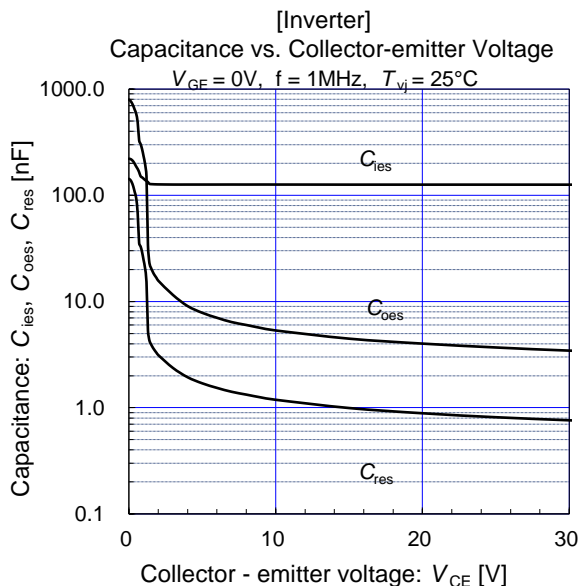
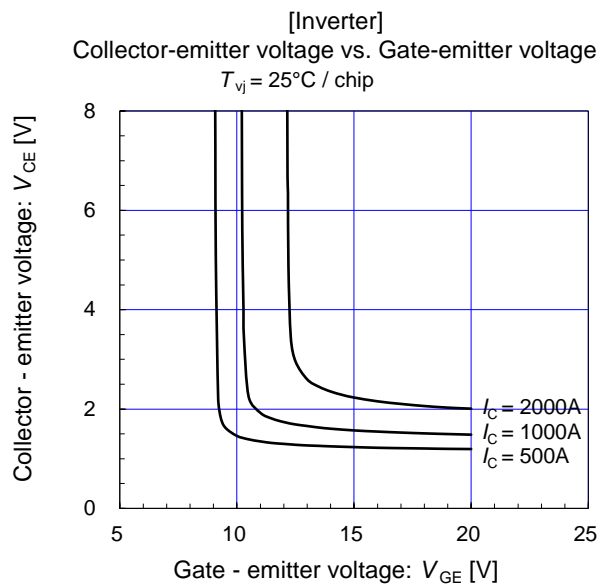
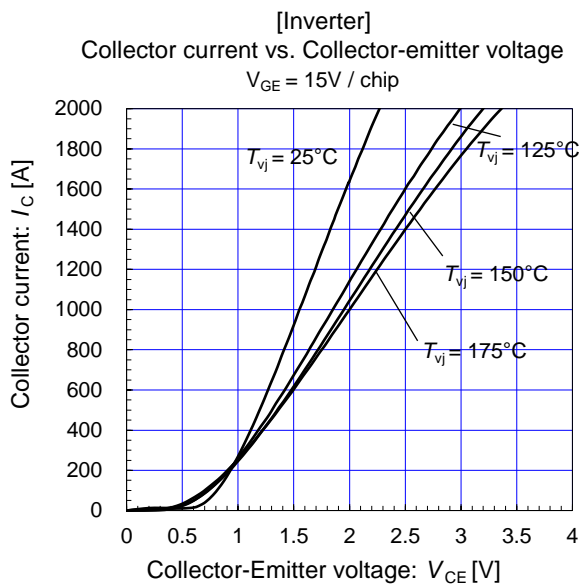
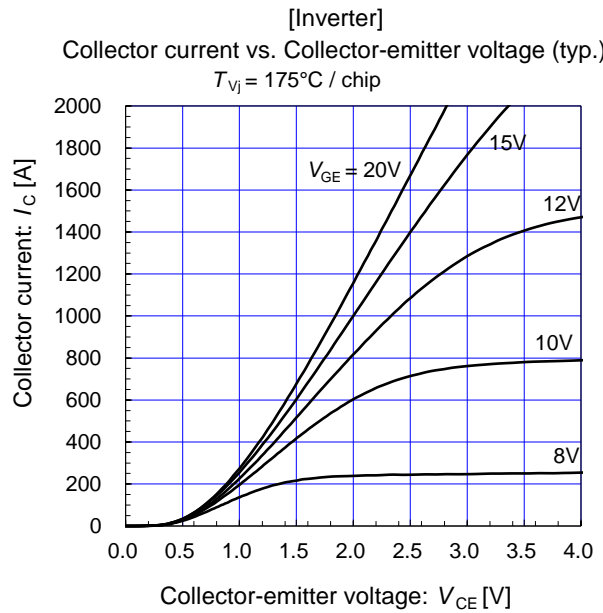
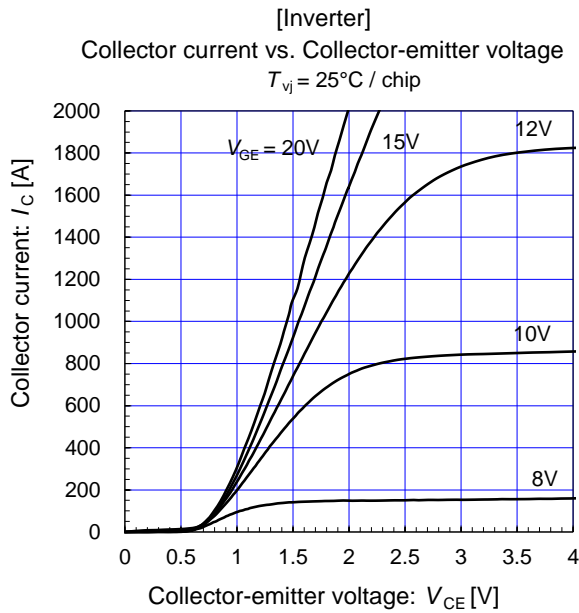
■ Thermal resistance characteristics

| Items | Symbols | Conditions | Characteristics | | | Units |
|---|---------------|-------------------------------|-----------------|--------|-------|-------|
| | | | min. | typ. | max. | |
| Thermal resistance junction to case(1 device) | $R_{th(j-c)}$ | Inverter IGBT | - | - | 0.018 | K/W |
| Thermal resistance case to heatsink(1 IGBT+1 FWD)(*1) | $R_{th(c-s)}$ | with 1 W/(m·K) thermal grease | - | 0.0125 | - | |

(*1) This is the value which is defined mounting on the additional heatsink with thermal grease.

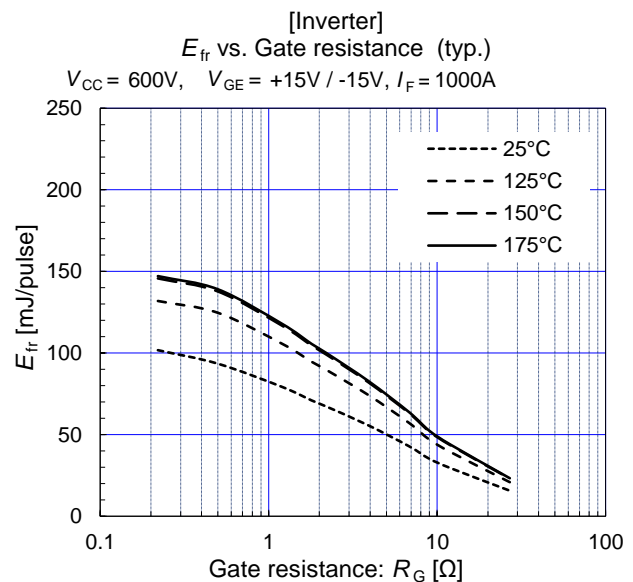
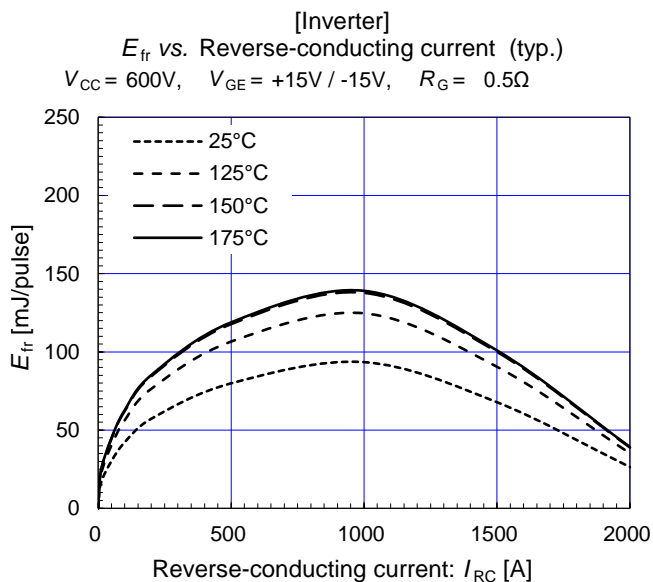
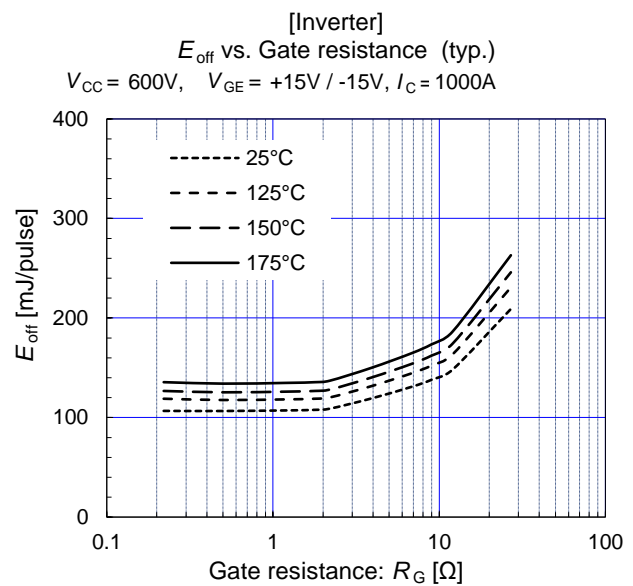
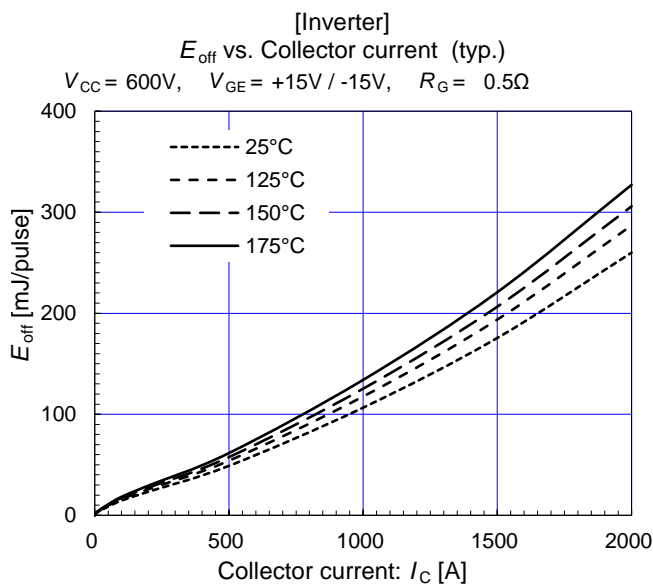
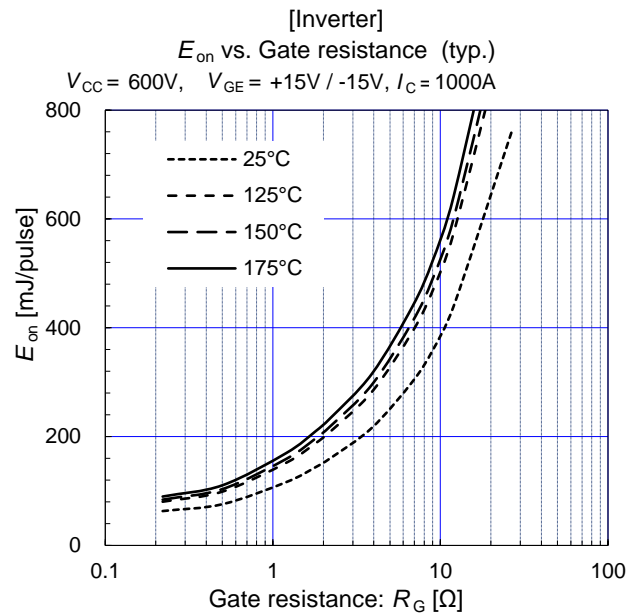
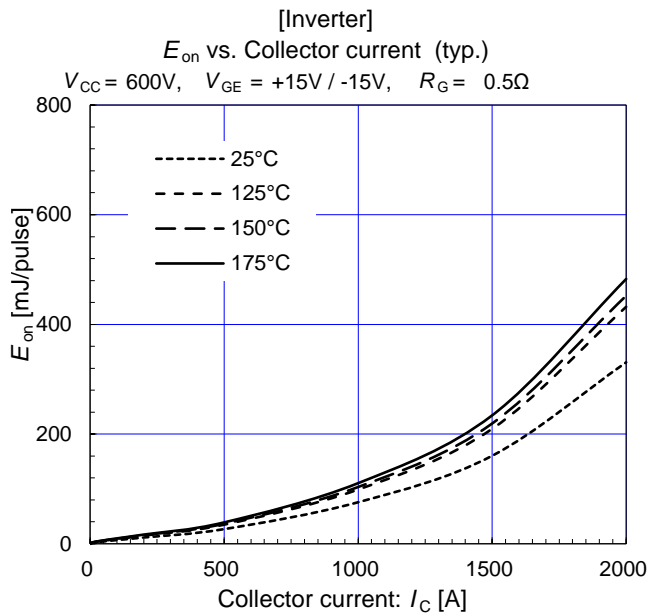
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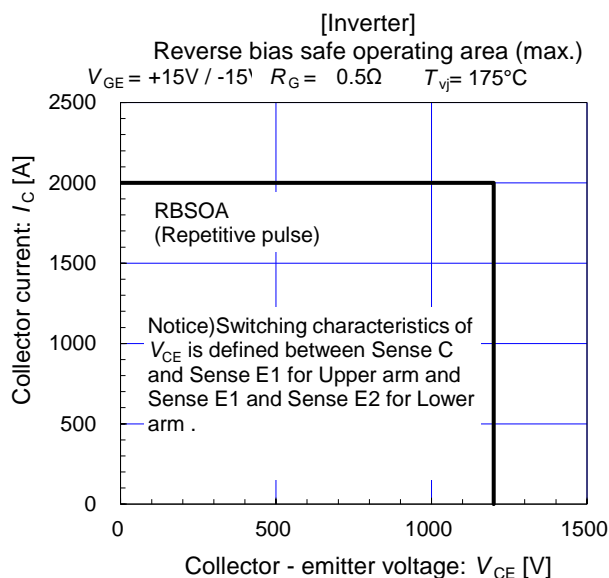
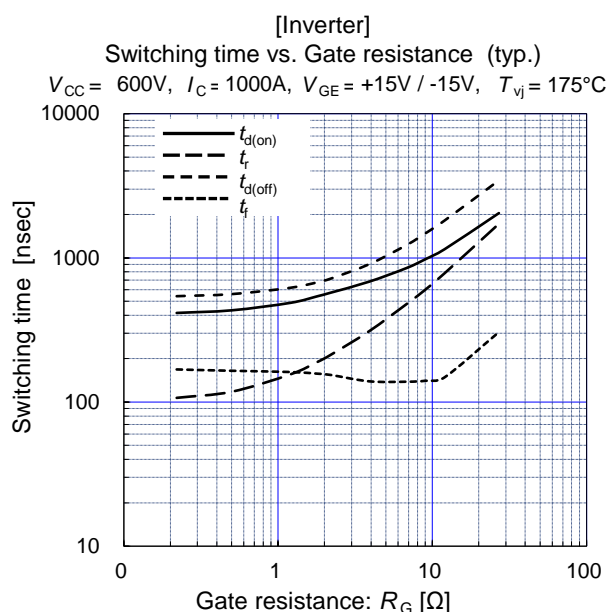
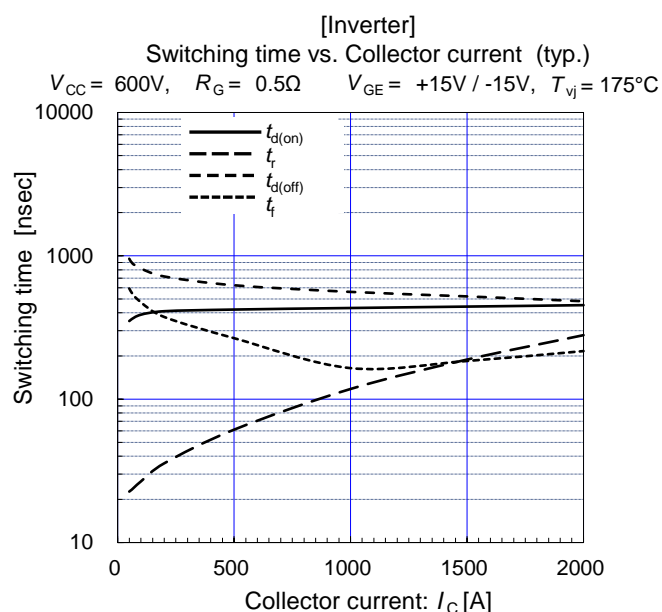
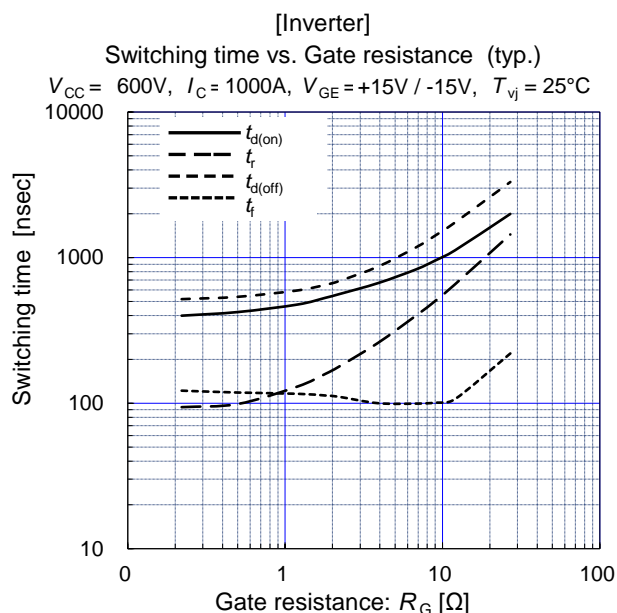
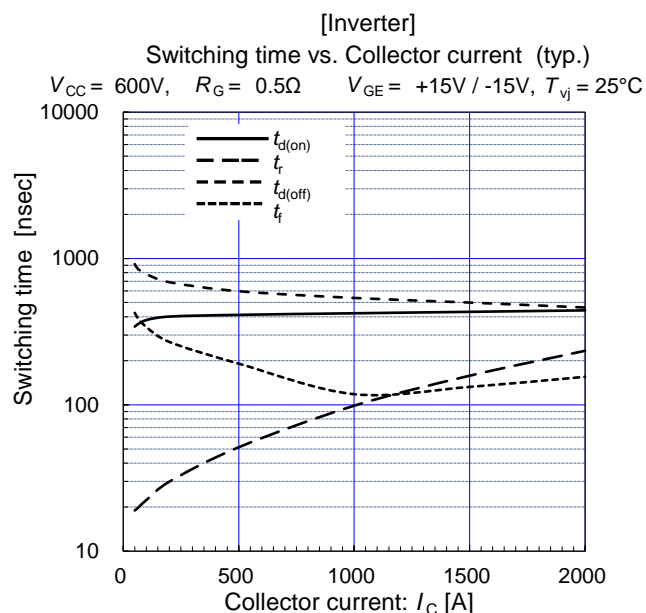
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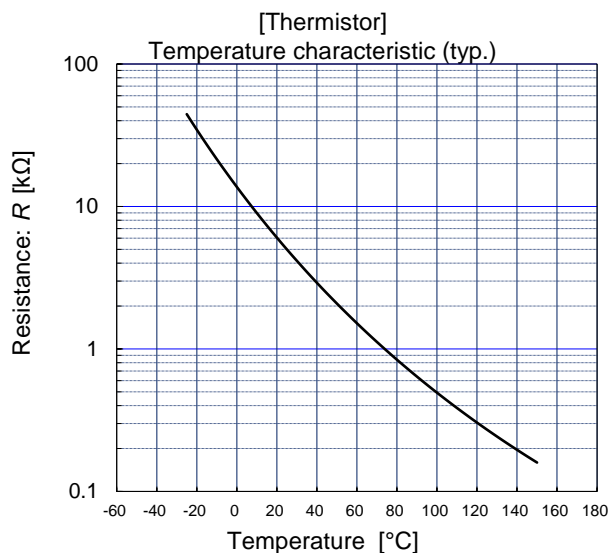
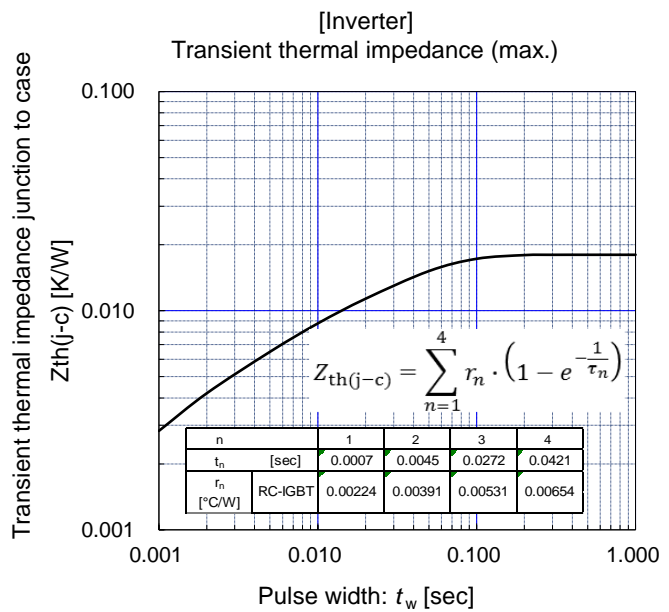
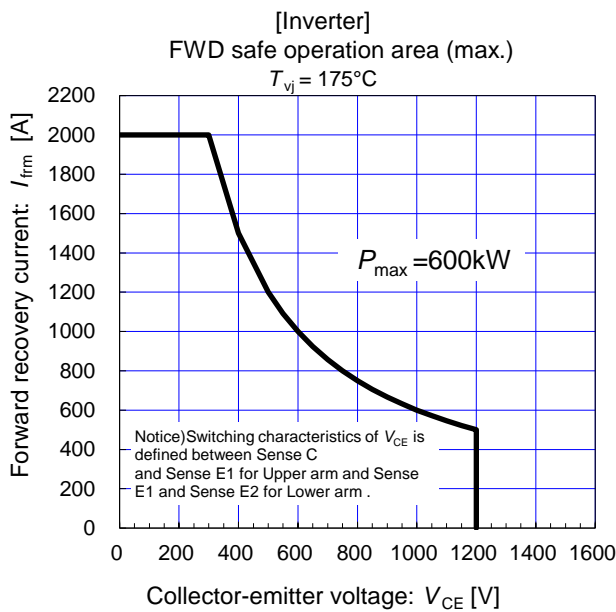
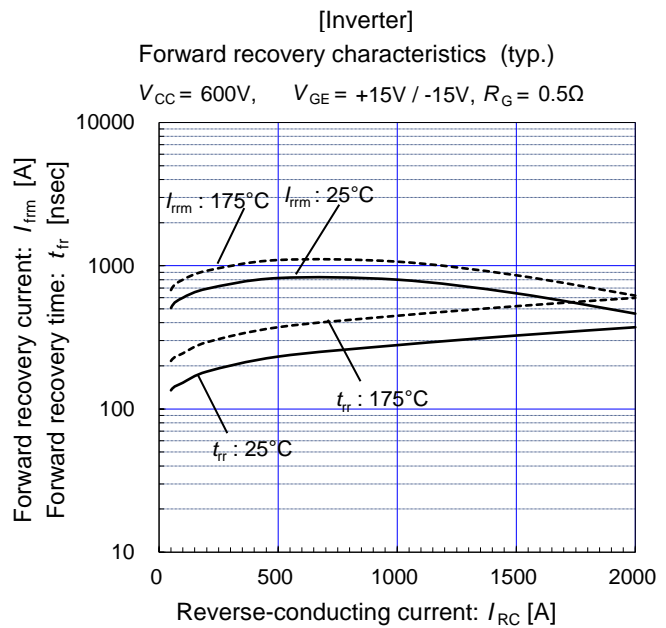
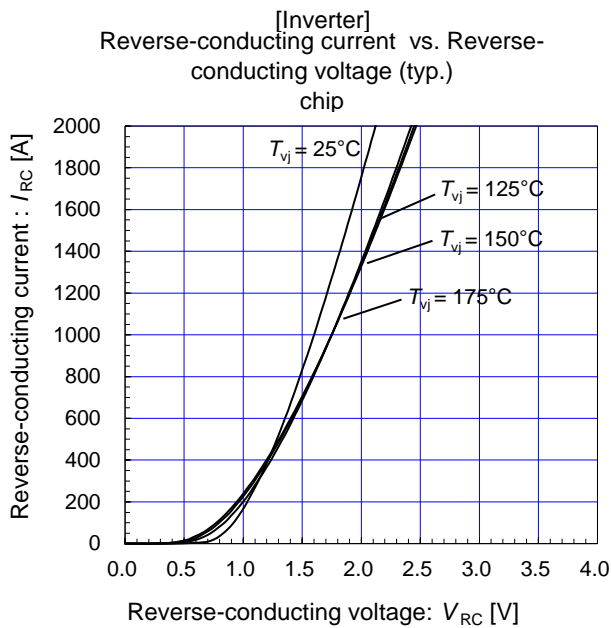
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